Filename: PMP20345RevB\_BOM.xls

| Filename: PMP2U345ReVB\_BOM. | Variant: 001 | Generated: 6/22/2016 2:32:34 PM | SVN path: SVN rev: \$Rev:: \$

UCC28700 High-side Buck Converter

\$

| Designator | Quantity | Value  | Description   | PackageReference           | PartNumber       | Manufacturer            | Alternate PartNumber  | Alternate Manufacturer |
|------------|----------|--------|---|----------------------------|------------------|-------------------------|-----------------------|------------------------|
| C1         | Quantity | 10uF   | CAP. AL. 10uF. 35V. +/-20%. TH  | CAPPR2-5x11                | UVR1V100MDD1TA   | Nichicon                | Alternate Partinumber | Alternate Manufacturer |
| C2         | 1        | 22pF   | CAP, CERM, 22pF, 50V, +/-5%, C0G/NP0, 0603  | 0603                       | 06035A220JAT2A   | AVX                     |                       |                        |
| C3, C4     |          | 6.8uF  | CAP. AL. 6.8uF. 400V. +/-20%. TH  | 8x11                       | 400AX6R8M8x11    | Rubycon                 | +                     |                        |
| C5         |          | 82uF   | CAP, AL, 82 µF, 63 V, +/- 20%, 0.51 ohm, TH   | D6.3xL11mm                 | UPV1E820MGD1TD   | Nichicon                |                       |                        |
| D1         | 1        | 100V   | Diode, Ultrafast, 100V, 0.15A, SOD-123  | SOD-123                    | 1N4148W-7-F      | Diodes Inc.             |                       |                        |
| D2         | 1        | 600V   | DIODE FAST REC 600V 1A DO214AC  | SMA                        | ES1J-TP          | Diodes Inc.             |                       |                        |
| D3         | 1        | 600V   | Diode, Switching-Bridge, 600 V, 1 A, MICRODIP_4   | MICRODIP 4                 | MDB6S            | Fairchild Semiconductor |                       |                        |
| D4         | 1        | 600V   | Diode, Ultrafast, 600V, 1A, SMB   | SMB                        | MURS160-13-F     | Diodes Inc.             |                       |                        |
| D6         |          | 20V    | Diode, Zener, 20 V. 550 mW, SMB   | SMB                        | 1SMB5932BT3G     | ON Semiconductor        |                       |                        |
| L1         | 1        | 1mH    | Inductor, Unshielded Drum Core, Ferrite, 1mH, 0.25A, 4.38 ohm. TH                       | D6 x 8.5mm                 | 7447462102       | Wurth Elektronik eiSos  |                       |                        |
| L2         | 1        | 330uH  | Inductor, Wirewound, Ferrite, 330 µH, 1.4 A, 0.3 ohm, TH                                | TH, Dia 10.5mm             | 7447480331       | Wurth Elektronik        |                       |                        |
| Q1         | 1        | 600V   | MOSFET N-CH 600V 1.3A TO252   | DPAK                       | AOD1N60          | AOS                     |                       | None                   |
| R1, R2     | 2        | 100k   | RES, 100 k, 0.1%, 0.1 W, 0603   | 0603                       | RG1608P-104-B-T5 | Susumu Co Ltd           |                       |                        |
| R3         | 1        | 8.87k  | RES, 8.87 k, 0.1%, 0.1 W, 0603  | 0603                       | RT0603BRD078K87L | Yageo America           |                       |                        |
| R4         | 1        | 511    | RES, 511 ohm, 1%, 0.1W, 0603  | 0603                       | CRCW0603511RFKEA | Vishay-Dale             |                       |                        |
| R5         | 1        | 3.0    | RES, 3.0, 5%, 0.75 W, AEC-Q200 Grade 0, 2010  | 2010                       | CRCW20103R00JNEF | Vishay-Dale             |                       |                        |
| R6         | 1        | 49.9k  | RES, 49.9 k, 1%, 0.75 W, AEC-Q200 Grade 0, 2010   | 2010                       | CRCW201049K9FKEF | Vishay-Dale             |                       |                        |
| R7         | 1        | 2.00   | RES, 2.00, 1%, 0.75 W, AEC-Q200 Grade 0, 2010   | 2010                       | CRCW20102R00FKEF | Vishay-Dale             |                       |                        |
| R8, R9     | 2        | 3.3Meg | RES, 3.3Meg ohm, 5%, 0.25W, 1206  | 1206                       | CRCW12063M30JNEA | Vishay-Dale             |                       |                        |
| RF1        | 1        | 4.7    | RES, 4.7 ohm, 5%, 1W, Fusible, TH   | Axial resistor             | FKN1WSJR-52-4R7  | Yageo America           |                       |                        |
| TP1, TP2   | 2        | Red    | Test Point, Miniature, Red, TH  | Red Miniature<br>Testpoint | 5000             | Keystone                |                       |                        |
| TP3, TP4   | 2        | Black  | Test Point, TH, Miniature, Black  | Keystone5001               | 5001             | Keystone                | Equivalent            | Any                    |
| U1         | 1        |        | Constant-Voltage, Constant-Current Controller With<br>Primary-Side Regulation, DBV0006A | DBV0006A                   | UCC28700DBVR     | Texas Instruments       | UCC28700DBVT          | Texas Instruments      |

## Notes:

Unless otherwise noted in the Alternate PartNumber and/or Alternate Manufacturer columns, all parts may be substituted with equivalents.

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